Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Plastic

Overall Length:

0.250 inches

Terminal Length:

0.560 inches

Overall Height:

0.250 inches

Overall Width:

0.185 inches

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-40.0 breakdown voltage, collector-to-base, emitter open and -40.0 breakdown voltage, collector-to-emitter, base open and -6.0 emitter

to base voltage, static, collector open

Current Rating Per Characteristic:

10.00 milliamperes all primaries

Power Rating Per Characteristic:

310.0 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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